

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	95622	gate\$1 adj (insulat\$3 or dielectric or oxide)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:44
L2	1366070	semiconduct\$3 or silicon	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:44
L3	495610	etch\$3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:45
L4	1401	((boron adj trichloride) or (Bcl3 or "bcl.sub.3")) same (chlorine or cl2 or "cl.sub.2") same (oxygen or o2 or "o.sub.2")	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:48
L5	2925807	((impurity or dop\$3) near2 region\$1) or source or drain	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:50
L6	19849	ldd or (light\$2 adj2 dop\$3 adj2 (drain or source))	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:51
L7	55079	selective\$2 near3 3	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:51
L8	23289	7 same (gate\$1 or conduct\$3 or titanium or ti)	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:54
L9	74898	1 same 2	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:54
L10	281657	(5 or 6) same 2	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:56

L11	1054	3 same 4	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 13:56
L12	14	(8 same 11) and 9 and 10	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 14:06
L13	128	11 and 8 and 9 and 10	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 14:06
L14	114	13 not 12	US-PGPUB; USPAT; USOCR; EPO; JPO; IBM_TDB	OR	ON	2005/07/24 14:07